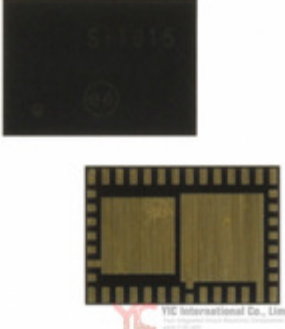



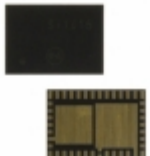




	<h2>SI1000-C-GM</h2>
	<p>Hersteller-Teilenummer: SI1000-C-GM</p> <p>Hersteller / Marke: Energy Micro (Silicon Labs)</p> <p>Teil der Beschreibung: IC RF TXRX+MCU ISM<1GHZ 42-WFQFN</p> <p>Datenblätter: 1.SI1000-C-GM.pdf 2.SI1000-C-GM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 905 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1000-C-GM
Hersteller	Energy Micro (Silicon Labs)
Beschreibung	IC RF TXRX+MCU ISM<1GHZ 42-WFQFN
Kategorie	RF / IF und RFID > RF-Transceiver ICS
Teilstatus	905 pcs Stock
Serie	-
Frequenz	240MHz ~ 960MHz
Betriebstemperatur	-40°C ~ 85°C
Art	TxRx + MCU
Empfindlichkeit	-121dBm
Verpackung / Gehäuse	42-WFQFN Exposed Pad
Spannungsversorgung	1.8 V ~ 3.6 V
Leistung	20dBm
Speichergröße	64kB Flash, 4.35kB RAM
Protokoll	EZRadioPro
Datenrate (Max)	256kbps
Serielle Schnittstellen	I ² C, SPI, UART
Strom - empfangen	18.5mA
RF Familie / Standard	General ISM < 1GHz
Modulation	FSK, GFSK, OOK
GPIO	22
Strom - senden	85mA
Verpackung	Tube

SI1000-C-GM ist neu im Original, Suche SI1000-C-GM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1000-C-GM Energy Micro (Silicon Labs) mit Garantie und Vertrauen. Anfrage SI1000-C-GM: Info@Y-IC.com

Sie können auch interessiert sein:

 Authorized Distributor SI100 3G TUBE 3M SCOTCH-WELD SURFACE INSENSITIVE	 Authorized Distributor SI100 1LB 3M SCOTCH-WELD SURFACE INSENSITIVE	 SI100 20G BTL 3M SURFACT INSENSITIVE INSTANT ADHE	 SI1000-E-GM2 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-VFLGA
 SI1000-CSA2-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN	 Not Actual Photo YIC International Co., Limited. SI1000-E-GMR SILICON SILICON LGA42	 SI1000-ESA2-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN	 SI1000-ESA2-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN

heiße Teile

Mehr

⊗ SI1002-C-GMR	↔ SI1003-C-GM	⇒ SI1011X-T1-GE3	D SI1011X-T1-GE3	⇒ SI1012CR-T1-GE3
⊣ SI1012CR-T1-GE3	⊗ SI1012R-T1	D SI1012R-T1-E3	⇒ SI1012R-T1-E3	⇒ SI1012R-T1-GE3
⊗ SI1012R-T1-GE3	⊣ SI1012X-T1	⊗ SI1012X-T1-E3	↔ SI1012X-T1-E3	⇒ SI1012X-T1-GE3
D SI1012X-T1-GE3	⊗ SI1013CX-T1-GE3	⊣ SI1013CX-T1-GE3	⊗ SI1013R-T1	⇒ SI1013R-T1-E3
⇒ SI1013R-T1-E3	↔ SI1013R-T1-GE3	⊗ SI1013R-T1-GE3	⊣ SI1013X-T1	⇒ SI1013X-T1-E3
↔ SI1013X-T1-E3	⇒ SI1013X-T1-GE3	D SI1013X-T1-GE3	⊗ SI1016CX-T1-GE3	⊣ SI1016CX-T1-GE3
⊗ SI1016X-T1-E3	D SI1016X-T1-E3	⇒ SI1016X-T1-GE3	↔ SI1016X-T1-GE3	⇒ SI1016X2-T1-GE3
⊣ SI1021R-T1	⊗ SI1021R-T1-E3	↔ SI1021R-T1-E3	⇒ SI1022R-T1	⇒ SI1022R-T1-E3
⊗ SI1022R-T1-E3	⊣ SI1022R-T1-GE3	⊗ SI1022R-T1-GE3	D SI1022R-T1-E3	⇒ SI1023CX-T1-GE3
↔ SI1023CX-T1-GE3	⊗ SI1023X-T1	⊣ SI1023X-T1-E3	⊗ SI1023X-T1-E3	⇒ SI1023X-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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